

**LISTING OF CLAIMS:**

1-13. (Canceled)

14. (Previously presented): An electronic device comprising:

a first base comprising a first conductive portion and a second conductive portion, said first conductive portion containing a first metal or metal compound having a first equilibrium electrode potential, said second conductive portion being electrically connected to said first conductive portion and containing a second metal or metal compound having a second equilibrium electrode potential;

an underlying layer formed on said first base; and

a reflective portion formed on a surface of said underlying layer, said reflective portion comprising a plurality of projections or recesses;

wherein said underlying layer comprises:

coating portions provided at positions corresponding to said plurality of projections or recesses, wherein said coating portion comprises chromium molybdenum oxide; and

an underlying layer main portion formed using photosensitive material, said underlying layer main portion covering said coating portions.

15. (Previously presented): An electronic device as claimed in claim 14, wherein said first base comprises a supporting member, and wherein said first conductive portion is formed on said supporting member, and said second conductive portion is formed so as to lie on said first conductive portion.

16. (Original): An electronic device as claimed in claim 15, wherein said first conductive portion is formed on an insulating film.

17. (Previously presented): An electronic device as claimed in claim 14, wherein said first base comprises:

a supporting member;  
said first conductive portion formed on said supporting member;  
wherein said insulating film having a hole for electrically connecting said first and second conductive portions; and  
said second conductive portion electrically connected to said first conductive portion through said hole.

18. (Previously presented): An electronic device as claimed in claim 16, wherein said insulating film comprises silicon nitride or silicon dioxide.

19-23. (Canceled)

24. (Previously presented): An electronic device as claimed in claim 15, wherein said first and second conductive portions form at least part of a gate electrode, a gate bus, a source electrode or a source bus.

25. (Previously presented): An electronic device as claimed in claim 24, wherein said first conductive portion comprises molybdenum as said first metal or metal compound, and

wherein said second conductive portion comprises aluminum as said second metal or metal compound.

26. (Canceled)

27. (Previously presented): An electronic device comprising:

a first base comprising a first conductive portion and a second conductive portion, said first conductive portion containing a first metal or metal compound having a first equilibrium electrode potential, said second conductive portion being electrically connected to said first conductive portion and containing a second metal or metal compound having a second equilibrium electrode potential, wherein said first base comprises a supporting member, wherein said first conductive portion is formed on said supporting member and said second conductive portion is formed so as to lie on said first conductive portion, wherein said first conductive portion is at least part of a gate terminal, and wherein said second conductive portion is at least part of a gate bus;

an underlying layer formed on said first base, wherein said underlying layer comprises coating portions provided at positions corresponding to said plurality of projections or recesses; and an underlying layer main portion formed using photosensitive material, said underlying layer main portion covering said coating portions; and

a reflective portion formed on a surface of said underlying layer, said reflective portion comprising a plurality of projections or recesses.

28. (Previously presented): An electronic device comprising:

a first base comprising a first conductive portion and a second conductive portion, said first conductive portion containing a first metal or metal compound having a first equilibrium electrode potential, said second conductive portion being electrically connected to said first conductive portion and containing a second metal or metal compound having a second equilibrium electrode potential, wherein said first base comprises a supporting member, wherein said first conductive portion is formed on said supporting member and said second conductive portion is formed so as to lie on said first conductive portion, wherein said first conductive portion is at least part of a source terminal, and wherein said second conductive portion is at least part of a gate electrode of an ESD transistor;

an underlying layer formed on said first base, wherein said underlying layer comprises coating portions provided at positions corresponding to said plurality of projections or recesses; and an underlying layer main portion formed using photosensitive material, said underlying layer main portion covering said coating portions; and

a reflective portion formed on a surface of said underlying layer, said reflective portion comprising a plurality of projections or recesses.

29. (Previously presented): An electronic device as claimed in claim 27, wherein said first conductive portion comprises indium oxide as said first metal or metal compound, and wherein said second conductive portion comprises aluminum or molybdenum as said second metal or metal compound.

30. (Canceled)

31. (Canceled)

32. (Previously presented): An image display device comprising an electronic device as claimed in claim 14.

33. (Previously presented): An electronic device comprising:

a first base comprising a first conductive portion, said first conductive portion containing a first metal or metal compound having a first equilibrium electrode potential, wherein said first conductive portion is formed on an insulating film;

an underlying layer formed on said first base; and

a reflective portion formed on a surface of said underlying layer, said reflective portion comprising a plurality of projections or recesses;

wherein said underlying layer comprises:

coating portions provided at positions corresponding to said plurality of projections or recesses, wherein said coating portion comprises chromium molybdenum oxide; and

an underlying layer main portion formed using photosensitive material, said underlying layer main portion covering said coating portions.

34. (Previously presented): An electronic device as claimed in claim 33, wherein said first base comprises a support member, and wherein said insulating film is formed on said supporting member, and said first conductive portion is formed on said insulating film.

35. (Previously presented): An electronic device as claimed in claim 33, wherein said first conductive portion is at least part of a gate terminal.

36. (Previously presented): An electronic device as claimed in claim 33, wherein said first conductive portion is at least part of a source terminal.

37. (Previously presented): An electronic device as claimed in claim 33, wherein said insulating film comprises silicon nitride or silicon dioxide.